

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

**TC74LVX240F, TC74LVX240FW, TC74LVX240FT  
TC74LVX244F, TC74LVX244FW, TC74LVX244FT****Octal Bus Buffer**

TC74LVX240 Inverted, 3-State Outputs

TC74LVX244 Non-Inverted, 3-State Outputs

Note: xxxFW (JEDEC SOP) is not available in Japan.

The TC74LVX240,244F/ FW/ FT is a high-speed CMOS OCTAL BUS BUFFER fabricated using silicon gate CMOS technology.

Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation. This device is suitable for low-voltage and battery operated systems.

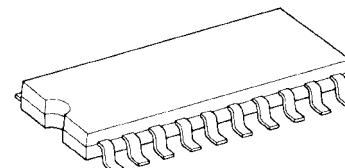
The TC74LVX240 is an inverting 3-state buffer while the TC74LVX244 is non-inverting. Both devices have two active-low output enables. These devices are designed to be used in such applications as 3-state memory address drivers.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

**Features**

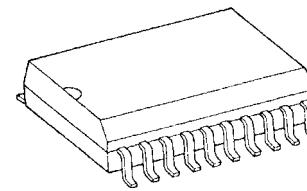
- High-speed:  $t_{pd} = 4.7$  ns (typ.) ( $V_{CC} = 3.3$  V)
- Low power dissipation:  $I_{CC} = 4 \mu A$  (max) ( $T_a = 25^\circ C$ )
- Input voltage level:  $V_{IL} = 0.8$  V (max) ( $V_{CC} = 3$  V)  
 $V_{IH} = 2.0$  V (min) ( $V_{CC} = 3$  V)
- Power-down protection provided on all inputs
- Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- Low noise:  $VO_{LP} = 0.8$  V (max)
- Pin and function compatible with 74HC240/244

TC74LVX240F, TC74LVX244F



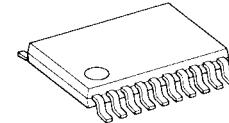
SOP20-P-300-1.27

TC74LVX240FW, TC74LVX244FW



SOL20-P-300-1.27

TC74LVX240FT, TC74LVX244FT



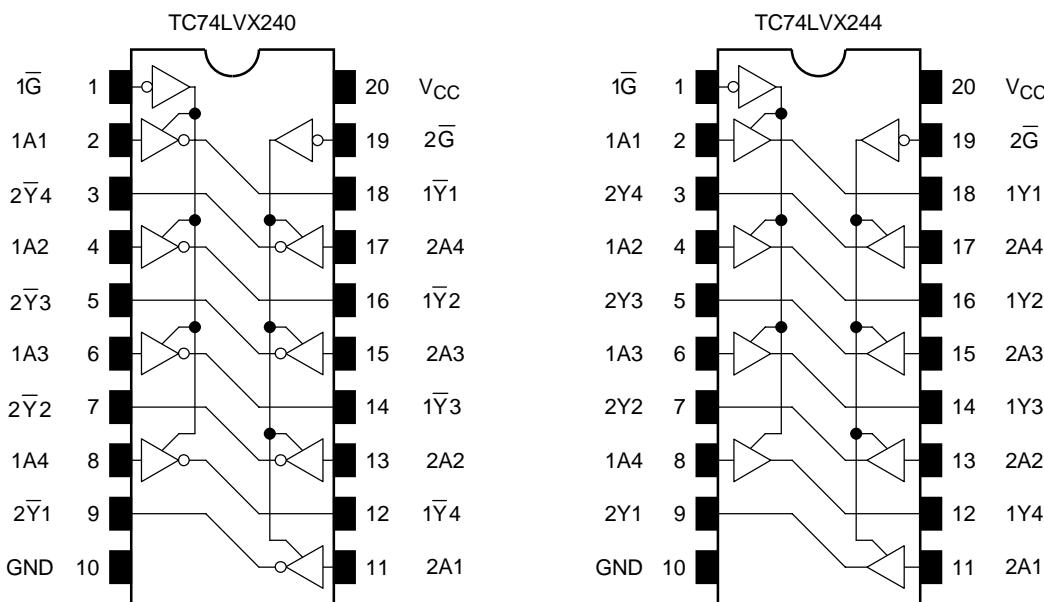
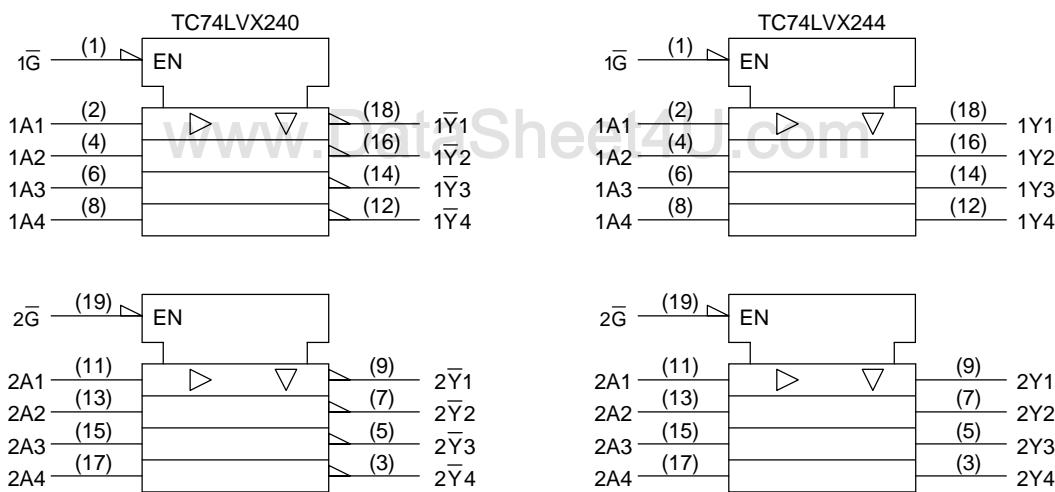
TSSOP20-P-0044-0.65

**Weight**

SOP20-P-300-1.27: 0.22 g (typ.)

SOL20-P-300-1.27: 0.46 g (typ.)

TSSOP20-P-0044-0.65: 0.08 g (typ.)

**Pin Assignment (top view)****IEC Logic Symbol****Truth Table**

Inputs		Outputs	
$\bar{G}$	$A_n$	$Y_n$ (244)	$\bar{Y}_n$ (240)
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don't care

Z: High impedance

**Maximum Ratings**

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	I <sub>OK</sub>	±20	mA
DC output current	I <sub>OUT</sub>	±25	mA
DC V <sub>CC</sub> /ground current	I <sub>CC</sub>	±75	mA
Power dissipation	P <sub>D</sub>	180	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

**Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 3.6	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

**Electrical Characteristics****DC Characteristics**

Characteristics		Symbol	Test Condition	V <sub>CC</sub> (V)	Ta = 25°C			Ta = -40 to 85°C		Unit	
					Min	Typ.	Max	Min	Max		
Input voltage	H-level	V <sub>IH</sub>	—	2.0	1.5	—	—	1.5	—	V	
				3.0	2.0	—	—	2.0	—		
				3.6	2.4	—	—	2.4	—		
	L-level	V <sub>IL</sub>	—	2.0	—	—	0.5	—	0.5		
				3.0	—	—	0.8	—	0.8		
				3.6	—	—	0.8	—	0.8		
Output voltage	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 µA	2.0	1.9	2.0	—	1.9	V	
				I <sub>OH</sub> = -50 µA	3.0	2.9	3.0	—	2.9		
				I <sub>OH</sub> = -4 mA	3.0	2.58	—	—	2.48		
	L-level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 µA	2.0	—	0	0.1	—		
				I <sub>OL</sub> = 50 µA	3.0	—	0	0.1	—		
				I <sub>OL</sub> = 4 mA	3.0	—	—	0.36	—		
3-State output		I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	3.6	—	—	±0.25	—	±2.5	µA	
Off-state current		I <sub>IN</sub>		3.6	—	—	±0.1	—	±1.0	µA	
Input leakage current		I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	3.6	—	—	4.0	—	40.0	µA	
Quiescent supply current											

**AC Characteristics (input:  $t_r = t_f = 3 \text{ ns}$ )**

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit		
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Typ.	Max			
Propagation delay time (TC74LVX240)	t <sub>pLH</sub>	—	2.7	15	—	5.7	10.1	1.0	12.5	
				50	—	8.2	13.6	1.0	16.0	
	t <sub>pHL</sub>		3.3 ± 0.3	15	—	4.3	6.2	1.0	7.5	
				50	—	6.8	9.7	1.0	11.0	
Propagation delay time (TC74LVX244)	t <sub>pLH</sub>	—	2.7	15	—	6.1	11.4	1.0	13.5	
				50	—	8.6	14.9	1.0	17.0	
	t <sub>pHL</sub>		3.3 ± 0.3	15	—	4.7	7.1	1.0	8.5	
				50	—	7.2	10.6	1.0	12.0	
Output enable time	t <sub>pZL</sub>	R <sub>L</sub> = 1 kΩ	2.7	15	—	7.1	13.8	1.0	16.5	
				50	—	9.6	17.3	1.0	20.0	
	t <sub>pZH</sub>		3.3 ± 0.3	15	—	5.5	8.8	1.0	10.5	
				50	—	8.0	12.3	1.0	14.0	
Output disable time	t <sub>pLZ</sub>	R <sub>L</sub> = 1 kΩ	2.7	50	—	11.6	16.0	1.0	19.0	
			3.3 ± 0.3	50	—	9.7	11.4	1.0	13.0	
Output to output skew	t <sub>osLH</sub>	(Note 1)	2.7	50	—	—	1.5	—	1.5	
			3.3 ± 0.3	50	—	—	1.5	—	1.5	
Input capacitance	C <sub>IN</sub>	(Note 2)			—	4	10	—	10	
Output capacitance	C <sub>OUT</sub>	—			—	6	—	—	pF	
Power dissipation capacitance (Note 3)	C <sub>PD</sub>	TC74LVX240	—	—	17	—	—	—	pF	
		TC74LVX244	—	—	19	—	—	—		

Note 1: Parameter guaranteed by design.

(t<sub>osLH</sub> = |t<sub>pLHm</sub> - t<sub>pLHn</sub>|, t<sub>osHL</sub> = |t<sub>pHLm</sub> - t<sub>pHLn</sub>|)

Note 2: Parameter guaranteed by design.

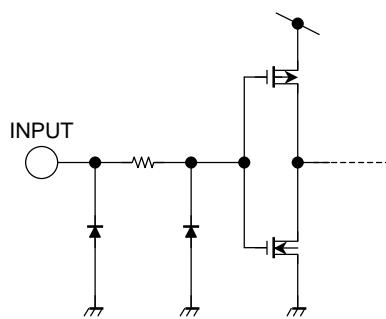
Note 3: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$$

**Noise Characteristics (Ta = 25°C, input: t<sub>r</sub> = t<sub>f</sub> = 3 ns, C<sub>L</sub> = 50 pF)**

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Typ.	Limit	Unit
Quiet output maximum dynamic	V <sub>OLP</sub>	—	3.3	0.5	0.8	V
Quiet output minimum dynamic	V <sub>OLV</sub>	—	3.3	-0.5	-0.8	V
Minimum high level dynamic input voltage	V <sub>IHD</sub>	—	3.3	—	2.0	V
Maximum low level dynamic input voltage	V <sub>ILD</sub>	—	3.3	—	0.8	V

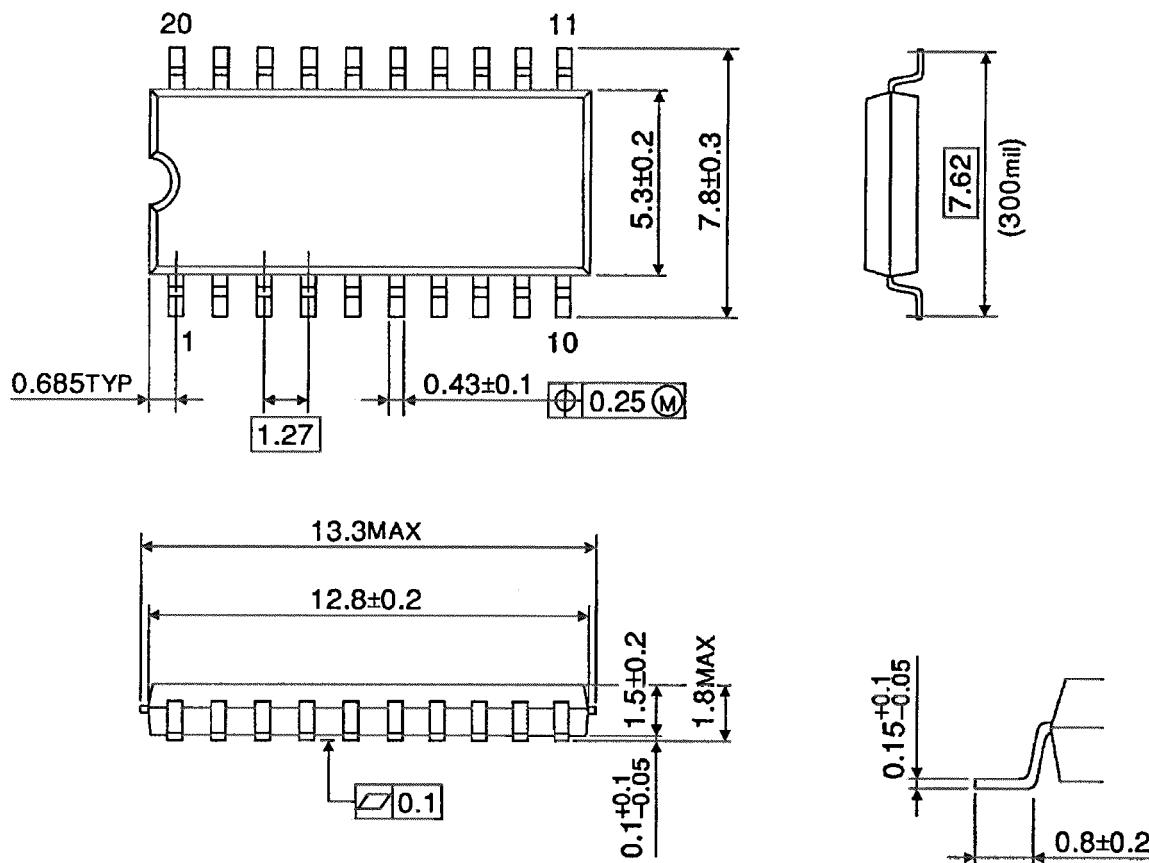
**Input Equivalent Circuit**

www.DataSheet4U.com

**Package Dimensions**

SOP20-P-300-1.27

Unit : mm

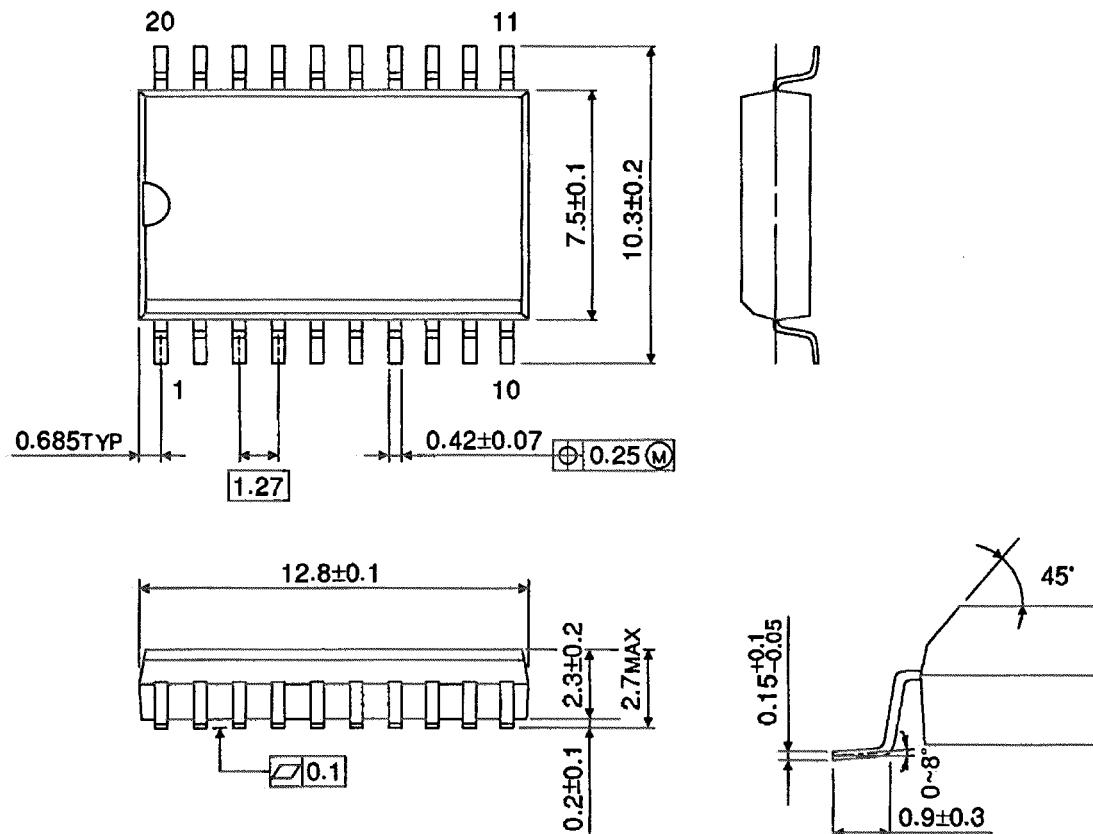


Weight: 0.22 g (typ.)

**Package Dimensions**

SOL20-P-300-1.27

Unit : mm

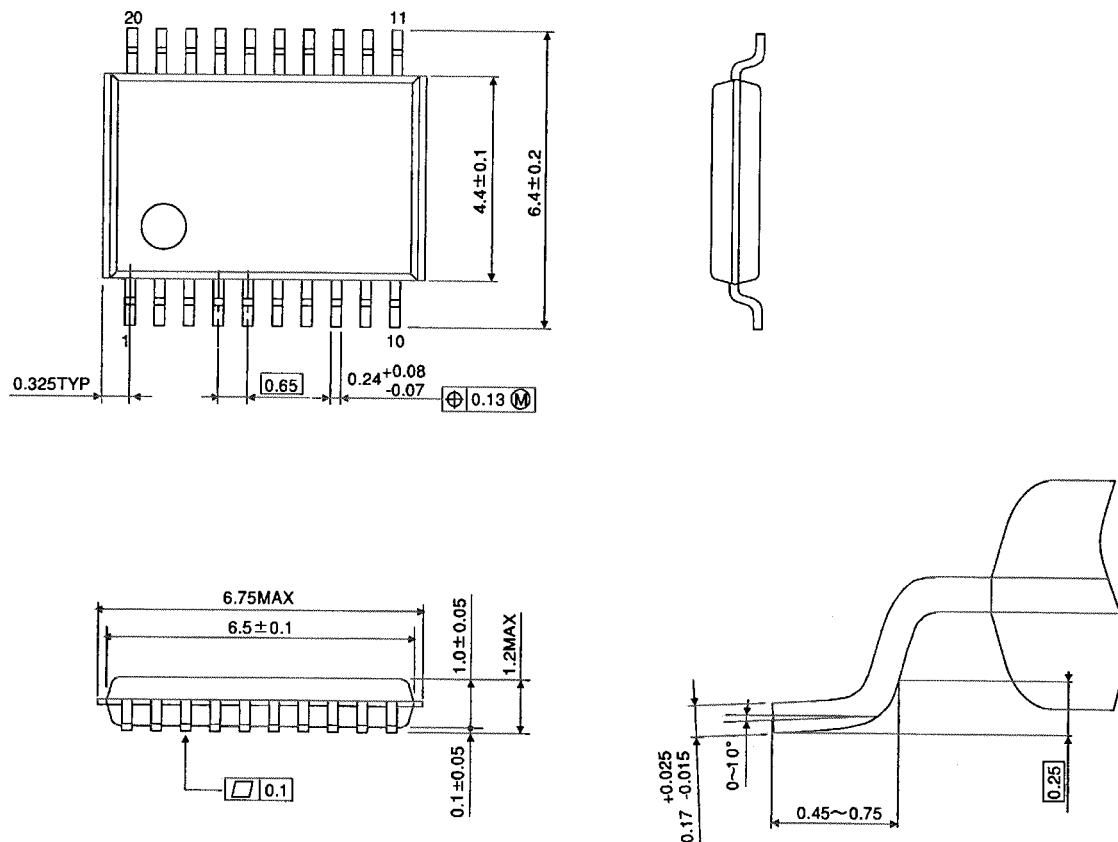


Weight: 0.46 g (typ.)

**Package Dimensions**

TSSOP20-P-0044-0.65

Unit : mm



Weight: 0.08 g (typ.)

[www.DataSheet4U.com](http://www.DataSheet4U.com)

## **RESTRICTIONS ON PRODUCT USE**

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.  
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.